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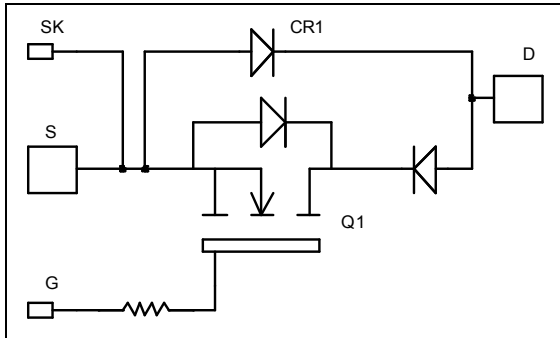
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*Single switch
Series & parallel diodes
MOSFET Power Module*

$V_{DSS} = 1000V$
 $R_{DSon} = 65m\Omega$ typ @ $T_j = 25^\circ C$
 $I_D = 145A$ @ $T_c = 25^\circ C$



Application

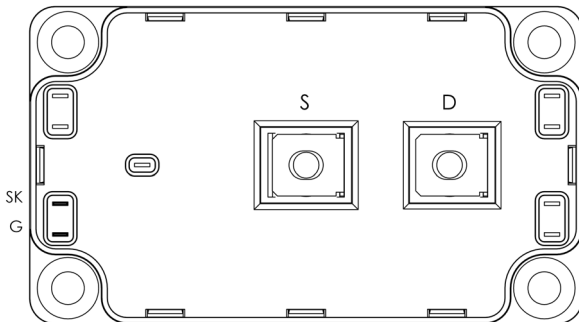
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration
- AlN substrate for improved thermal performance

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant



All ratings @ $T_j = 25^\circ C$ unless otherwise specified

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V_{DSS}	Drain - Source Breakdown Voltage	1000	V
I_D	Continuous Drain Current	$T_c = 25^\circ C$	145
		$T_c = 80^\circ C$	110
I_{DM}	Pulsed Drain current	580	
V_{GS}	Gate - Source Voltage	± 30	V
R_{DSon}	Drain - Source ON Resistance	78	$m\Omega$
P_D	Maximum Power Dissipation	$T_c = 25^\circ C$	3250
I_{AR}	Avalanche current (repetitive and non repetitive)	30	A
E_{AR}	Repetitive Avalanche Energy	50	mJ
E_{AS}	Single Pulse Avalanche Energy	3200	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

Electrical Characteristics

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>	<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$			400	μA
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 72.5A$		65	78	$m\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 20mA$	3		5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30V, V_{DS} = 0V$			± 400	nA

Dynamic Characteristics

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>	<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
C_{iss}	Input Capacitance	$V_{GS} = 0V$		28.5		nF
C_{oss}	Output Capacitance	$V_{DS} = 25V$		5.08		
C_{rss}	Reverse Transfer Capacitance	$f = 1MHz$		0.9		
Q_g	Total gate Charge	$V_{GS} = 10V$		1068		nC
Q_{gs}	Gate – Source Charge	$V_{Bus} = 500V$		136		
Q_{gd}	Gate – Drain Charge	$I_D = 145A$		692		
$T_{d(on)}$	Turn-on Delay Time	$V_{GS} = 15V$		18		ns
T_r	Rise Time	$V_{Bus} = 500V$		14		
$T_{d(off)}$	Turn-off Delay Time	$I_D = 145A$		140		
T_f	Fall Time	$R_G = 0.75\Omega$		55		
E_{on}	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 145A, R_G = 0.75\Omega$		4.8		mJ
E_{off}	Turn-off Switching Energy			2.9		
E_{on}	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 145A, R_G = 0.75\Omega$		8		mJ
E_{off}	Turn-off Switching Energy			3.9		
R_{thJC}	Junction to Case Thermal Resistance				0.038	$^{\circ}C/W$

Series diode ratings and characteristics

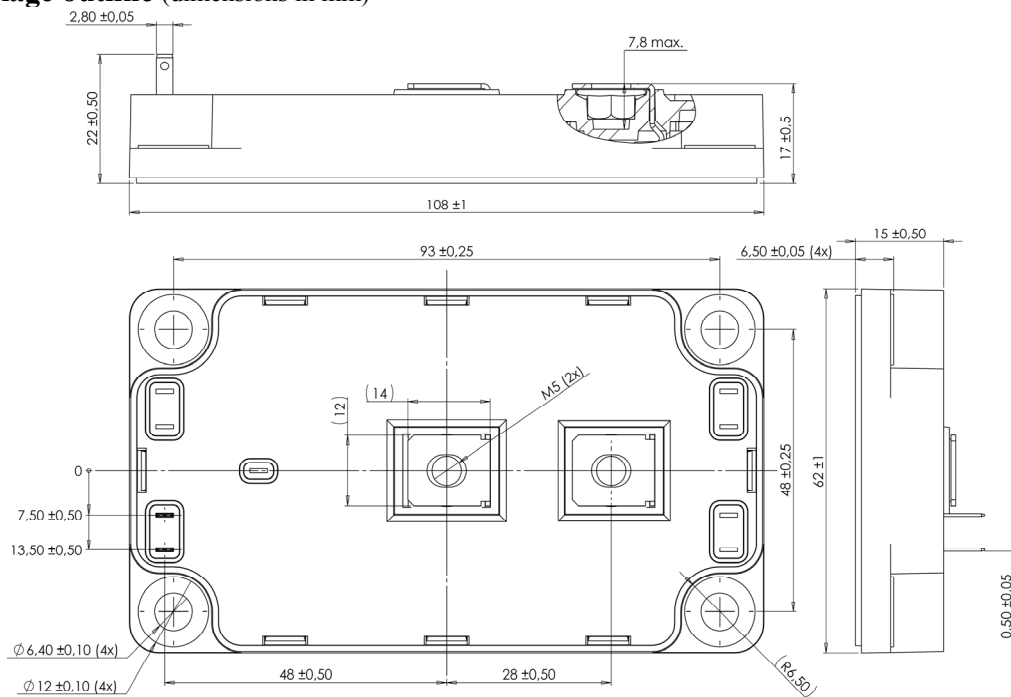
<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>	<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
V_{RRM}	Maximum Peak Repetitive Reverse Voltage		1000			V
I_{RM}	Maximum Reverse Leakage Current	$V_R = 1000V$			750	μA
I_F	DC Forward Current	$T_c = 80^{\circ}C$		240		A
V_F	Diode Forward Voltage	$I_F = 240A$		2	2.5	V
		$I_F = 480A$		2.2		
		$I_F = 240A$	$T_j = 125^{\circ}C$		1.7	
t_{rr}	Reverse Recovery Time	$I_F = 240A$ $V_R = 667V$ $di/dt = 800A/\mu s$	$T_j = 25^{\circ}C$		280	ns
			$T_j = 125^{\circ}C$		350	
Q_{rr}	Reverse Recovery Charge	$I_F = 240A$ $V_R = 667V$ $di/dt = 800A/\mu s$	$T_j = 25^{\circ}C$		3.04	μC
			$T_j = 125^{\circ}C$		14.4	
R_{thJC}	Junction to Case Thermal Resistance				0.23	$^{\circ}C/W$

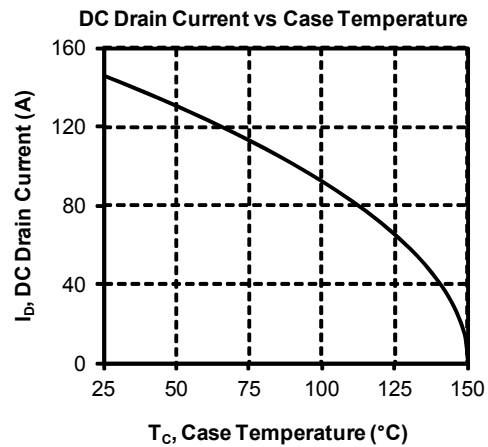
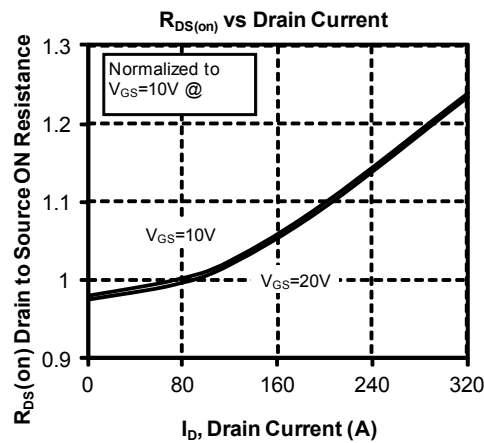
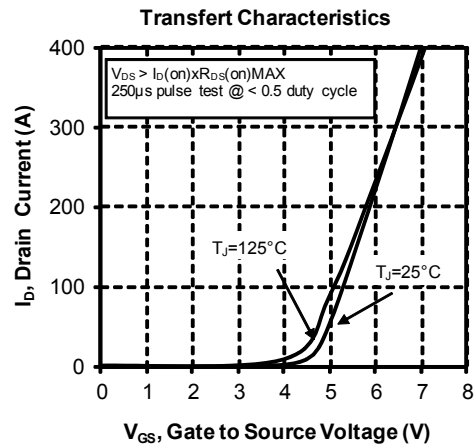
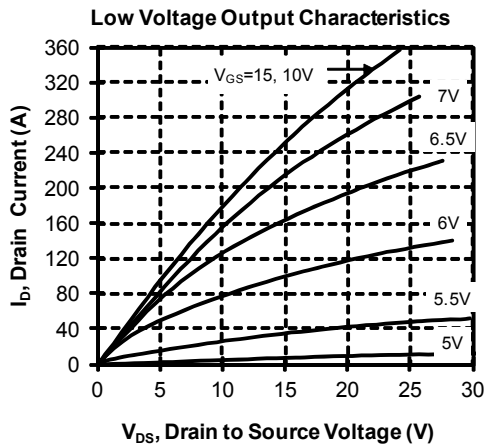
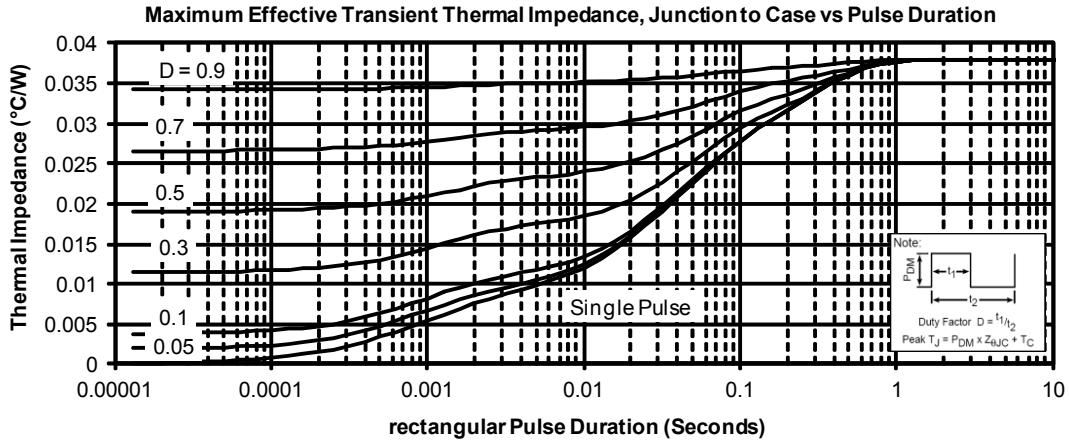
Parallel diode ratings and characteristics

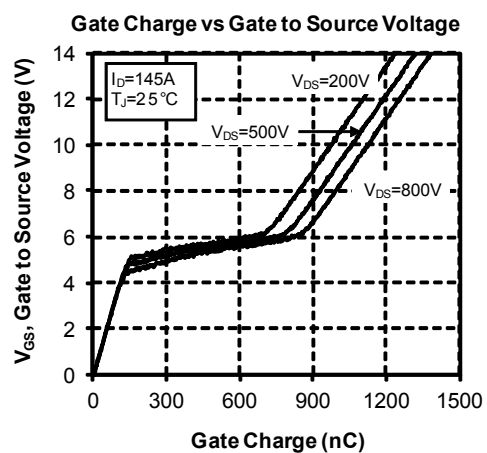
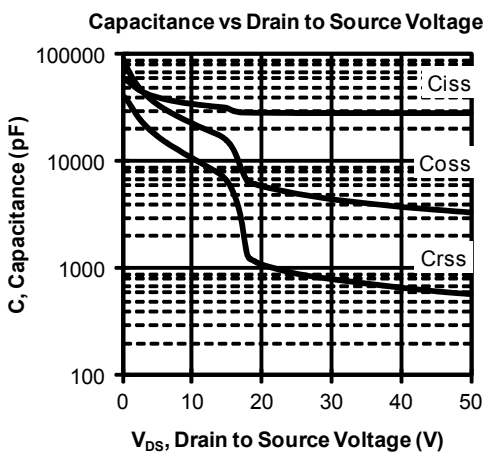
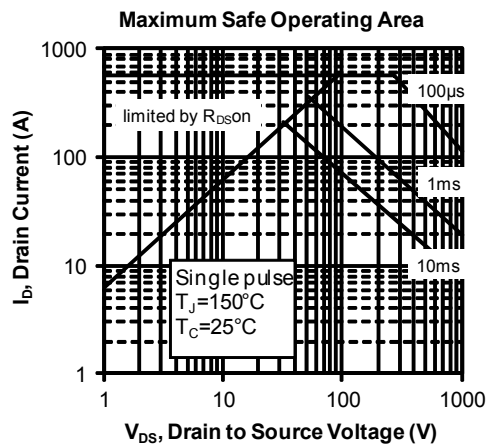
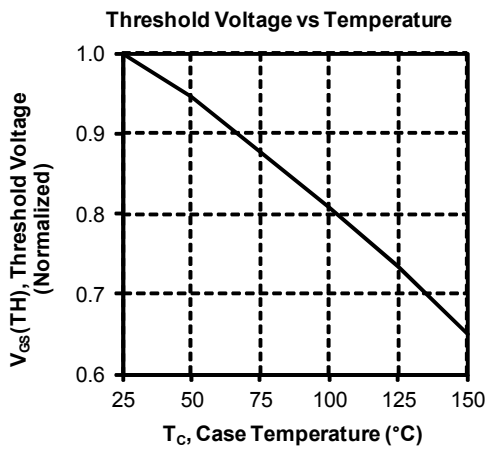
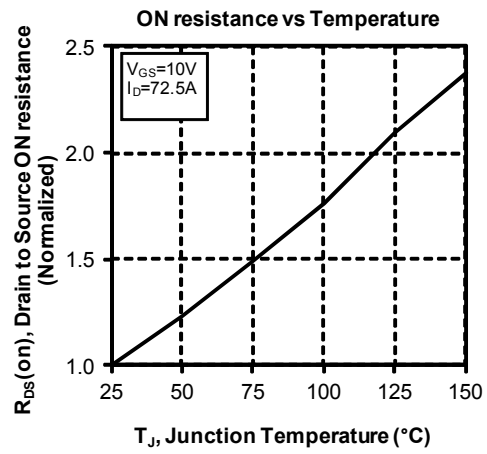
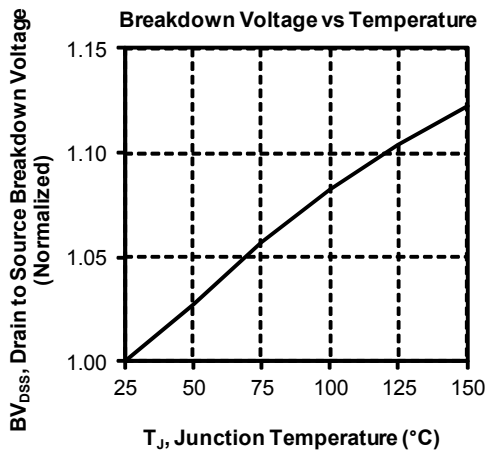
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			1000			V
I _{RM}	Maximum Reverse Leakage Current	V _R =1000V				750	μA
I _F	DC Forward Current	T _c = 80°C			240		A
V _F	Diode Forward Voltage	I _F = 240A			2	2.5	V
		I _F = 480A			2.2		
		I _F = 240A	T _j = 125°C		1.7		
t _{rr}	Reverse Recovery Time	I _F = 240A V _R = 667V di/dt = 800A/μs	T _j = 25°C		280		ns
	T _j = 125°C			350			
Q _{rr}	Reverse Recovery Charge		T _j = 25°C		3.04		
		T _j = 125°C		14.4			
R _{thJC}	Junction to Case Thermal Resistance					0.23	°C/W

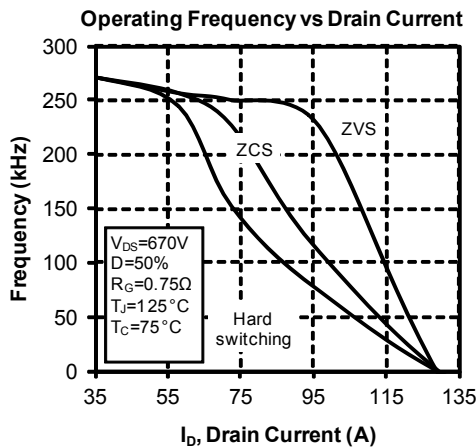
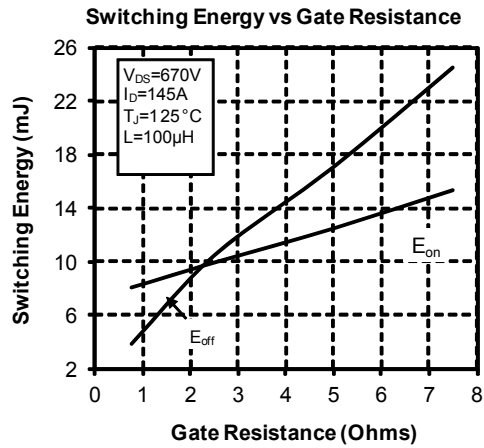
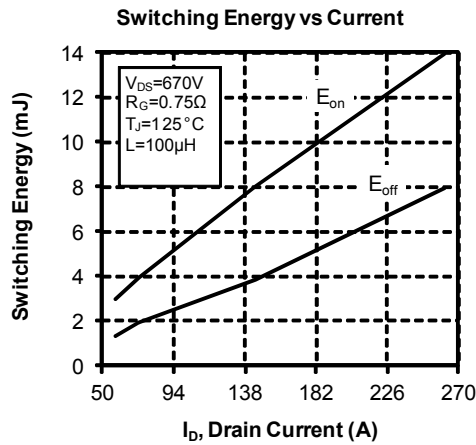
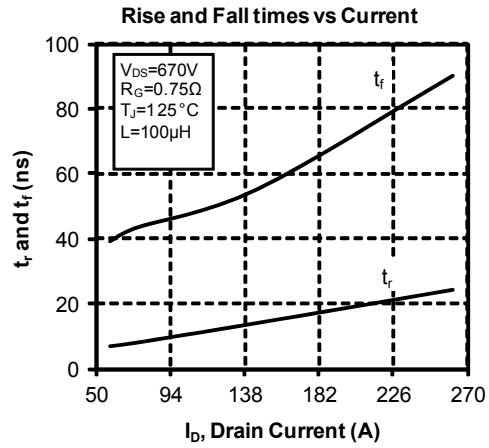
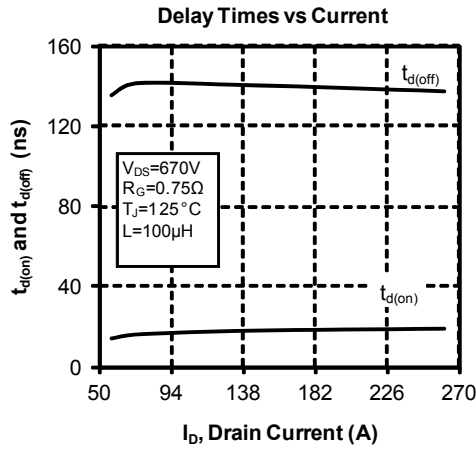
Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit
V _{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000		V
T _J	Operating junction temperature range			-40	150	°C
T _{JOP}	Recommended junction temperature under switching conditions			-40	T _{jmax} -25	
T _{STG}	Storage Temperature Range			-40	125	
T _C	Operating Case Temperature			-40	100	
Torque	Mounting torque	To Heatsink	M6	3	5	
		For terminals	M5	2	3.5	
Wt	Package Weight				300	g

SP6 Package outline (dimensions in mm)

 See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

Typical Performance Curve






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